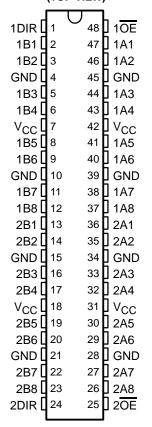
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- State-of-the-Art Advanced BiCMOS
 Technology (ABT) Widebus™ Design for
 2.5-V and 3.3-V Operation and Low
 Static-Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- High Drive (-32/64 mA at 3.3-V V_{CC})
- I_{off} and Power-Up 3-State Support Hot Insertion
- Use Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- Flow-Through Architecture Facilitates
 Printed Circuit Board Layout
- Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

description

The 'ALVTH16245 devices are 16-bit (dual-octal) noninverting 3-state transceivers designed for 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

SN54ALVTH16245 . . . WD PACKAGE SN74ALVTH16245 . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)



These devices can be used as two 8-bit transceivers or one 16-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When V_{CC} is between 0 and 1.2 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



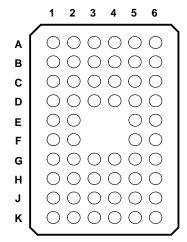
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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SN74ALVTH16245 . . . GQL PACKAGE (TOP VIEW)



terminal assignments

	1	2	3	4	5	6
Α	1DIR	NC	NC	NC	NC	1OE
В	1B2	1B1	GND	GND	1A1	1A2
С	1B4	1B3	Vcc	Vcc	1A3	1A4
D	1B6	1B5	GND	GND	1A5	1A6
E	1B8	1B7			1A7	1A8
F	2B1	2B2			2A2	2A1
G	2B3	2B4	GND	GND	2A4	2A3
н	2B5	2B6	Vcc	Vcc	2A6	2A5
J	2B7	2B8	GND	GND	2A8	2A7
K	2DIR	NC	NC	NC	NC	2OE

NC - No internal connection

ORDERING INFORMATION

TA	PACKA	.GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SSOP – DL	Tape and reel	SN74ALVTH16245DLR	ALVTH16245
–40°C to 85°C	TSSOP – DGG	Tape and reel	SN74ALVTH16245GR	ALVTH16245
-40°C to 85°C	TVSOP – DGV	Tape and reel	SN74ALVTH16245VR	VT245
	VFBGA – GQL	Tape and reel	SN74ALVTH16245QR	
–55°C to 125°C	CFP – WD	Tube	SNJ54ALVTH16245WD	SNJ54ALVTH16245WD

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

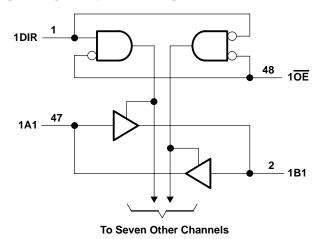
FUNCTION TABLE (each 8-bit section)

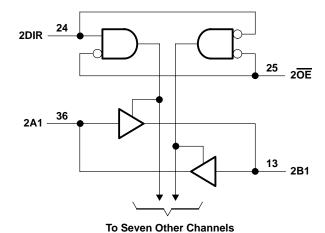
INP	UTS	ODEDATION			
ŌĒ	DIR	OPERATION			
L	L	B data to A bus			
L	Н	A data to B bus			
Н	X	Isolation			



SCES066G - JUNE 1996 - REVISED APRIL 2002

logic diagram (positive logic)





Pin numbers shown are for the DGG, DGV, DL, and WD packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} –0.5 V t	o 4.6 V
Input voltage range, V _I (see Note 1)	/ to 7 V
Voltage range applied to any output in the high or power-off state, VO (see Note 1)0.5 \	/ to 7 V
Output current in the low state, IO: SN54ALVTH16245	96 mA
SN74ALVTH16245 1	128 mA
Output current in the high state, IO: SN54ALVTH16245	-48 mA
SN74ALVTH16245	-64 mA
Input clamp current, I_{IK} ($V_I < 0$)	-50 mA
Output clamp current, I _{OK} (V _O < 0)	-50 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	70°C/W
DGV package	58°C/W
DL package 6	3°C/W
GQL package	12°C/W
Storage temperature range, T _{stg} 65°C to	150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.



SCES066G - JUNE 1996 - REVISED APRIL 2002

recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

				ALVTH1	6245	SN74	ALVTH1	6245	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		2.3		2.7	2.3		2.7	V
VIH	High-level input voltage		1.7		V	1.7			V
V _{IL}	Low-level input voltage			Š	0.7			0.7	V
VI	Input voltage		0	VCC	5.5	0	VCC	5.5	V
loн	High-level output current			1/	-6			-8	mA
la	Low-level output current			2	6			8	mΑ
lOL	Low-level output current; current duty cycle ≤ 5	50%; f ≥ 1 kHz		5	18			24	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q		10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
TA	Operating free-air temperature		-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

recommended operating conditions, $V_{\mbox{\footnotesize{CC}}}$ = 3.3 V \pm 0.3 V (see Note 3)

			SN54	ALVTH16245 SN74ALVTH16245			UNIT		
			MIN	TYP	MAX	MIN	TYP	MAX	UNII
Vcc	Supply voltage		3		3.6	3		3.6	V
VIH	High-level input voltage		2		7	2			V
V _{IL}	Low-level input voltage			Š	0.8			0.8	V
٧ _I	Input voltage		0	Vcc	5.5	0	VCC	5.5	V
lOH	High-level output current			7	-24			-32	mA
la.	Low-level output current			2	24			32	mA
lOL	Low-level output current; current duty cycle ≤ 5	50%; f≥1 kHz	, c	5	48			64	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	Q		10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200			200			μs/V
T _A	Operating free-air temperature	_	-55		125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SCES066G - JUNE 1996 - REVISED APRIL 2002

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

PARAMETER		TEOT 04	NUDITIONS	SN54	ALVTH1	6245	SN74	ALVTH1	6245		
PA	KAMEIEK	lesi co	ONDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT	
VIK		$V_{CC} = 2.3 \text{ V},$	I _I = -18 mA			-1.2			-1.2	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.	.2		V _{CC} -0.	2			
Vон		V _{CC} = 2.3 V	$I_{OH} = -6 \text{ mA}$	1.8						V	
		VCC = 2.3 V	$I_{OH} = -8 \text{ mA}$				1.8				
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OL} = 100 μA			0.2			0.2		
			$I_{OL} = 6 \text{ mA}$			0.4					
VOL		V _{CC} = 2.3 V	I _{OL} = 8 mA						0.4	V	
		VCC = 2.3 V	$I_{OL} = 18 \text{ mA}$			0.5					
			I _{OL} = 24 mA			2			0.5		
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND		3	±1			±1		
	Control inputs	$V_{CC} = 0 \text{ or } 2.7 \text{ V},$	V _I = 5.5 V		20	10			10		
Ц			V _I = 5.5 V		Z.	20			20	μΑ	
	A or B ports	$V_{CC} = 2.7 V$	VI = VCC		S	1			1		
			V _I = 0	Ċ	9	- 5			- 5		
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	Q	,				±100	μΑ	
I _{BHL} ‡		$V_{CC} = 2.3 \text{ V},$	V _I = 0.7 V		115			115		μΑ	
I _{BHH} §		$V_{CC} = 2.3 \text{ V},$	V _I = 1.7 V		-10			-10		μΑ	
IBHLO		$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	300			300			μΑ	
Івнно	#	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	-300			-300			μΑ	
{IEX}		$V{CC} = 2.3 \text{ V},$	V _O = 5.5 V			125			125	μΑ	
IOZ(PU	J/PD) [☆]	$V_{CC} \le 1.2 \text{ V}, V_{O} = \frac{0.5}{OE} \text{ V}$ V _I = GND or V _{CC} , \overline{OE} =	to V _{CC} , don't care			±100			±100	μΑ	
		V _{CC} = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1		
ICC		$I_O = 0$,	Outputs low		2.3	4.5		2.3	4.5	mA	
			Outputs disabled		0.04	0.1		0.04	0.1		
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3.5			3.5		pF	
C _{io}		V _{CC} = 2.5 V,	V _O = 2.5 V or 0		8			8		pF	

[†] All typical values are at $V_{CC} = 2.5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

 $[\]P$ An external driver must source at least IBHLO to switch this node from low to high.

[#]An external driver must sink at least IBHHO to switch this node from high to low.

Current into an output in the high state when VO > VCC

^{*}High-impedance state during power up or power down

SCES066G - JUNE 1996 - REVISED APRIL 2002

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

PARAMETER		TEST C	ONDITIONS	SN54	ALVTH1	6245	SN74	ALVTH1	6245	UNIT
PAI	RAMETER	lEST CO	CNDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT
VIK		$V_{CC} = 3 V$,	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	VCC-0	2		V _{CC} -0	.2		
Vон		V _{CC} = 3 V	$I_{OH} = -24 \text{ mA}$	2						V
		1 vCC = 3 v	$I_{OH} = -32 \text{ mA}$				2			
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA			0.2			0.2	
			I _{OL} = 16 mA						0.4	
VOL			$I_{OL} = 24 \text{ mA}$			0.5				V
VOL		V _{CC} = 3 V	$I_{OL} = 32 \text{ mA}$						0.5	V
			$I_{OL} = 48 \text{ mA}$			0.55				
	_		$I_{OL} = 64 \text{ mA}$			2			0.55	
Control inputs		$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND		3	±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V		P. P. E.	10			10	
l _l			V _I = 5.5 V		7	20			20	μΑ
	A or B ports	VCC = 3.6 V	AI = ACC		2	1			1	
			V _I = 0		3	- 5			- 5	
I _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to 4.5 V	Q					±100	μΑ
I _{BHL} ‡		$V_{CC} = 3 V$,	V _I = 0.8 V	75			75			μΑ
I _{BHH} §		$V_{CC} = 3 V$,	V _I = 2 V	-75			-75			μΑ
IBHLO¶		$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	500			500			μΑ
I _{BHHO} #	#	$V_{CC} = 3.6 \text{ V},$	$V_I = 0$ to V_{CC}	-500			-500			μΑ
{IEX}		$V{CC} = 3 V$,	V _O = 5.5 V			125			125	μΑ
I _{OZ(PU/}	/PD) [☆]	$V_{CC} \le 1.2 \text{ V}, V_{O} = \frac{0.5}{\text{OE}} \text{ V}$ V _I = GND or V _{CC} , $\overline{\text{OE}}$ =	' to V _{CC} , don't care			±100			±100	μΑ
		V _{CC} = 3.6 V,	Outputs high		0.07	0.1		0.07	0.1	
Icc		$I_{O} = 0$,	Outputs low		3.2	5		3.2	5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.07	0.1		0.07	0.1	
ΔICC		V _{CC} = 3 V to 3.6 V, One Other inputs at V _{CC} or 0	input at V _{CC} – 0.6 V, GND			0.2			0.2	mA
Ci		V _{CC} = 3.3 V,	V _I = 3.3 V or 0		3.5			3.5		pF
C _{io}		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		8			8		pF

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

 $[\]P$ An external driver must source at least IBHLO to switch this node from low to high.

[#] An external driver must sink at least I_{BHHO} to switch this node from high to low.

Current into an output in the high state when V_O > V_{CC}

^{*}High-impedance state during power up or power down

 $[\]Box$ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

SCES066G - JUNE 1996 - REVISED APRIL 2002

switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	l 'Ŭ L	SN54ALVTH16245		SN74AL\	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	A or B	B or A	0.5	3.6	0.5	3.6	ns
t _{PHL}	AOIB		0.5	3.4	0.5	3.4	115
^t PZH	ŌĒ	A or B	1.5	4.9	1.5	4.9	ns
^t PZL	OE	AUIB	1.5	4	1	4	115
^t PHZ	ŌĒ	A or B	1.5	4.9	1.5	4.9	ns
^t PLZ	OE	7010	QΫ	4.2	1	4.2	115

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54AL	SN54ALVTH16245		SN74ALVTH16245		
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	UNIT	
t _{PLH}	A or B	B or A	0.5	3.1	0.5	3.1	ns	
^t PHL	AOIB		0.5	2.9	0.5	2.9		
^t PZH	ŌĒ	A or B	1	4.2	1	4.2	ns	
t _{PZL}	OE		15	3.5	1	3.5	110	
^t PHZ	ŌĒ	A or B	1.5	5.3	1.5	5.3	ns	
^t PLZ	OL	7010	1.5	5	1.5	5	113	

skew

 t_{DS} (pin or transition skew), $t_{DS} = |t_{PHL} - t_{PHL}|$

	$V_{CC} = 2.5 V$	V _{CC} = 3.3 V	UNIT
	TYP	TYP	UNIT
t _{ps} max	438	118	ps

t_{OST} = $|t_{p \oplus m} - t_{p \oplus n}|$, where Φ is any edge transition (high to low or low to high) measured between any two outputs (m or n) within any given device (see Note 4)

		V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT
		TYP	TYP	UNIT
	A–B	227	248	no
tost	В–А	223	243	ps

NOTE 4: One output switching, $T_A = 25^{\circ}C$

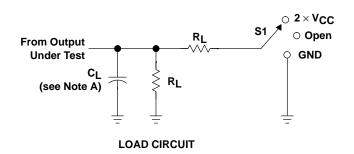
$t_{OSLH}/t_{OSLH} (common edge skew), t_{OSHL} = |t_{PHL}max - t_{PHL}min| (output skew for low-to-high transitions), and t_{OSLH} = |t_{PLH}max - t_{PLH}min| (output skew for high-to-low transitions) (see Note 4)$

		V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT
		TYP	TYP	
^t OSLH	A–B	210	145	ps
^t OSHL	A-B	243	351	
^t OSLH	B-A	207	136	no
t _{OSHL}	D-A	238	350	ps

NOTE 4: One output switching, $T_A = 25^{\circ}C$

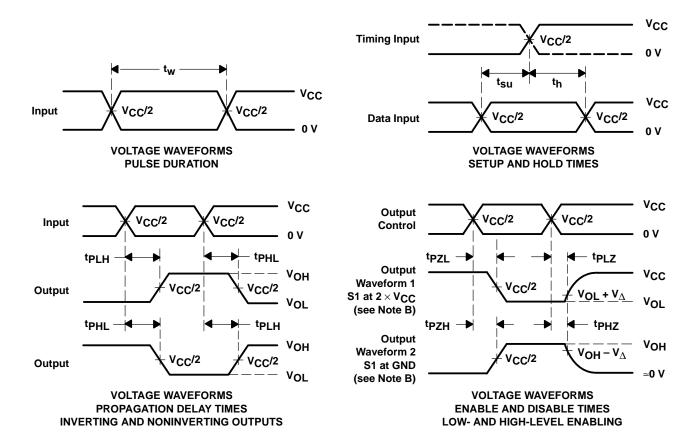


PARAMETER MEASUREMENT INFORMATION



TEST	S 1
tPLH/tPHL	Open
tPLZ/tPZL	2×V _{CC}
tPHZ/tPZH	GND

V _{CC}	CL	RL	$v_{\scriptscriptstyle\Delta}$
2.5 V ±0.2 V	30 pF	500 Ω	0.15 V
3.3 V ±0.3 V	50 pF	500 Ω	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2 ns. $t_{f} \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLZ and tpHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms







.com 4-Oct-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74ALVTH16245GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16245VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16245ZQLR	ACTIVE	VFBGA	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74ALVTH16245DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16245DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16245GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16245KR	ACTIVE	VFBGA	GQL	56	1000	TBD	SNPB	Level-1-240C-UNLIM
SN74ALVTH16245VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

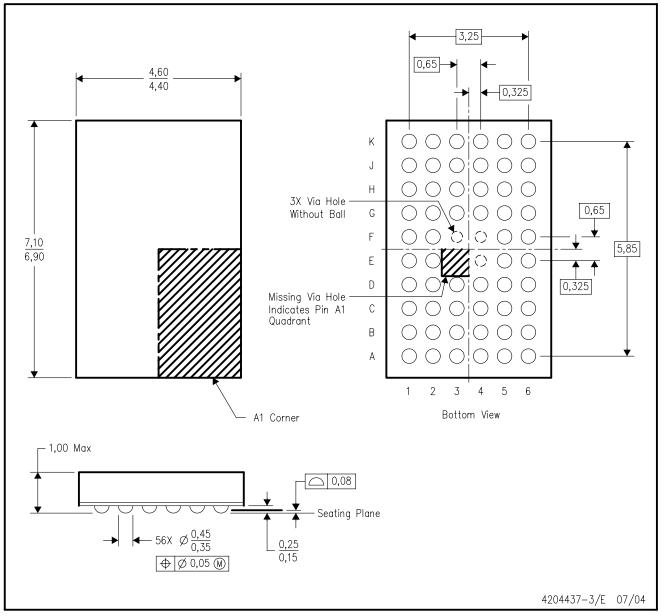
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

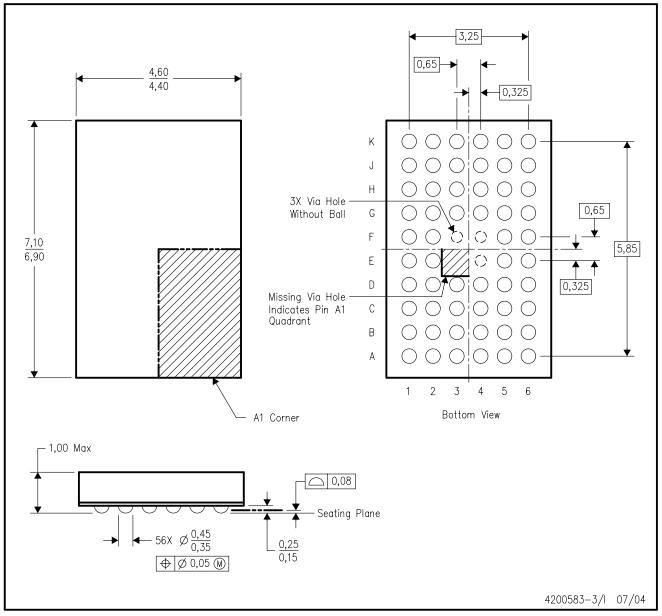
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DL (R-PDSO-G**)

48 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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